

FORM PTO-1449

LIST OF PATENTS AND PUBLICATIONS FOR
APPLICANT'S INFORMATION DISCLOSURE
STATEMENT

(Use several sheets if necessary)

ATTY. DOCKET NO.

10019853-1

APPLICATION NO. CONFIRMATION NO.

APPLICANT

Yong Chen et al

FILING DATE

GROUP

JC821 U.S. PRO
10/033408

12/26/01

REFERENCE DESIGNATION

U.S. PATENT DOCUMENTS

EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS
SA	1A	5,045,408	9/3/91	R. Stanley Williams et al	428	620
	1B					
	1C					
	1D					
	1E					
	1F					
	1G					
	1H					
	1I					
	1J					
	1K					

FOREIGN PATENT DOCUMENTS

		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS	TRANSLATION	
							YES	NO
	1L							
	1M							
	1N							
	1O							
	1P							

OTHER REFERENCES (including Author, Title, Date, Pertinent Pages, etc.)

SA	1Q	P.M. Petroff et al. "MBE and MOCVD Growth and Properties of Self-Assembling Quantum Dot Arrays in III-V Semiconductor Structures", Superlattices and Microstructures, Vol. 15, pp. 15-21 (1994)
SA	1R	Yong Chen et al, "Self-assembled growth of epitaxial erbium disilicide nanowires on silicon (001)", Applied Physics Letters, Vol. 76, No. 26, pp. 4004-4006 (26 June 2000)
SA	1S	K.L. Kavanagh et al, "High-temperature epitaxy of PtSi/Si(0 0 1)", Journal of Crystal Growth, Vol. 173 pp. 393-401 (1997)

EXAMINER

Shamim Ahmed

DATE CONSIDERED

8/20/03